

P54/74FCT3651C/D—P54/74FCT3652C/D

3.3 VOLT OCTAL TRANSCEIVER/REGISTER

FEATURES

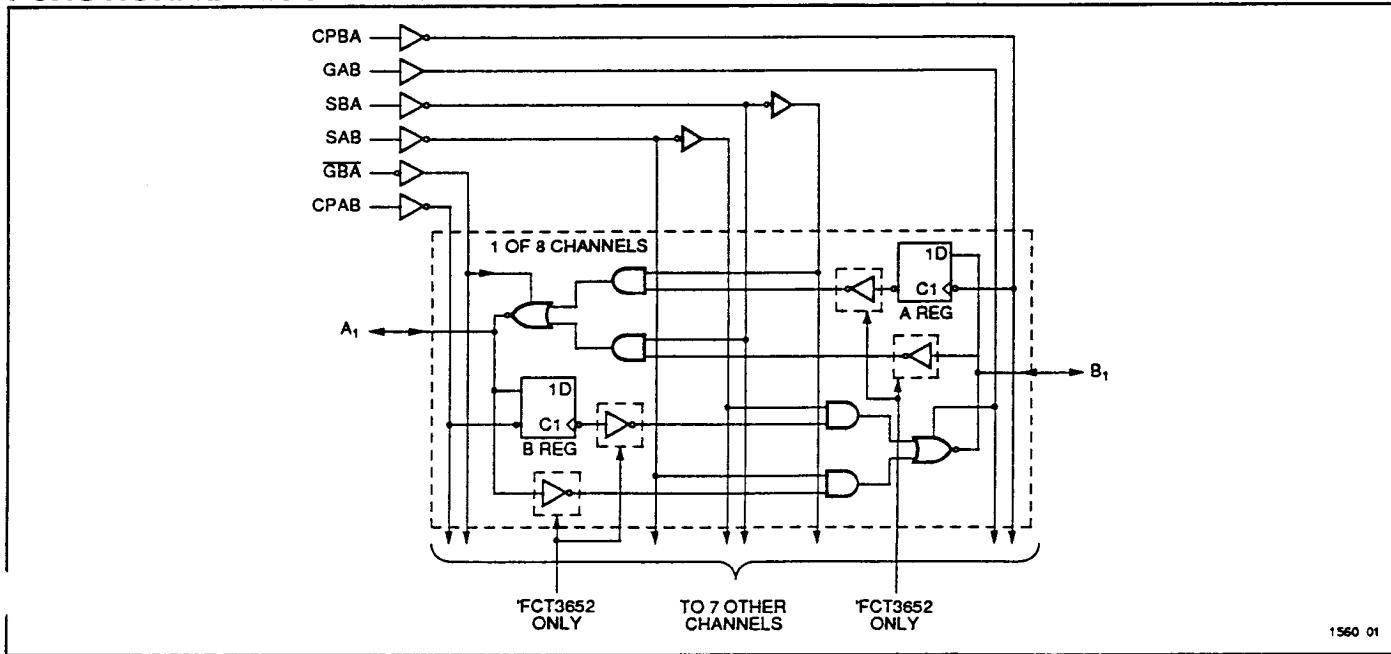
- Function and Drive Compatible with the Fastest TTL Logic
- Inputs and Outputs Interface with TTL Logic Levels
- $3.3V \pm 0.2V$ Power Supply and CMOS for Lowest Power Dissipation
- FCT3-D speed at 4.0ns max. (Com'l)
FCT3-C speed at 5.4ns max. (Com'l)
- Edge-rate Control Circuitry for Significantly Improved Switching Characteristics
- ESD protection exceeds 2000V
- 64 mA Sink Current (Com'l), 48 mA (MII)
15mA Source Current (Com'l), 12 mA (MII)
- Multiple Center Power and Ground Pins
- Input Clamp Diodes to Limit Bus Reflections
- Independent Register for A and B Buses
- Multiplexed Real-Time and Stored Data Transfer
- 3-State Outputs
- Manufactured in 0.4 micron PACE Technology™

DESCRIPTION

The 'FCT3651 and 'FCT3652 consist of bus transceiver circuits, D-type flip-flops and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal storage registers. GAB and GBA control pins are provided to control the transceiver functions. SAB and SBA control pins are provided to select either real-time or stored data transfer. The circuitry used for select control will eliminate the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. A low input level selects real-time data and a high selects stored data.

Data on the A or B data bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock pins (CPAB or CPBA), regardless of the select or enable control pins. When SAB and SBA are in the real-time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling GAB and GBA. In this configuration, each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state.

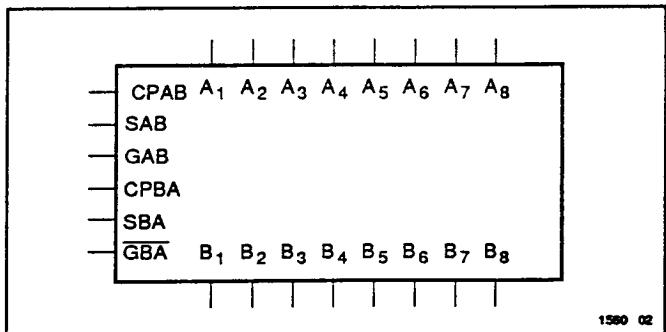
FUNCTIONAL BLOCK DIAGRAM



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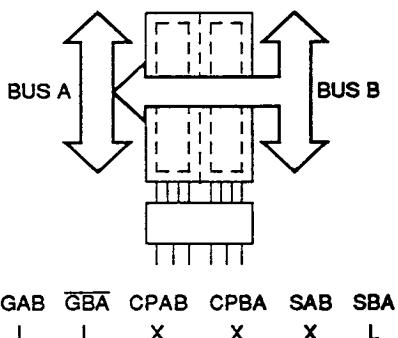
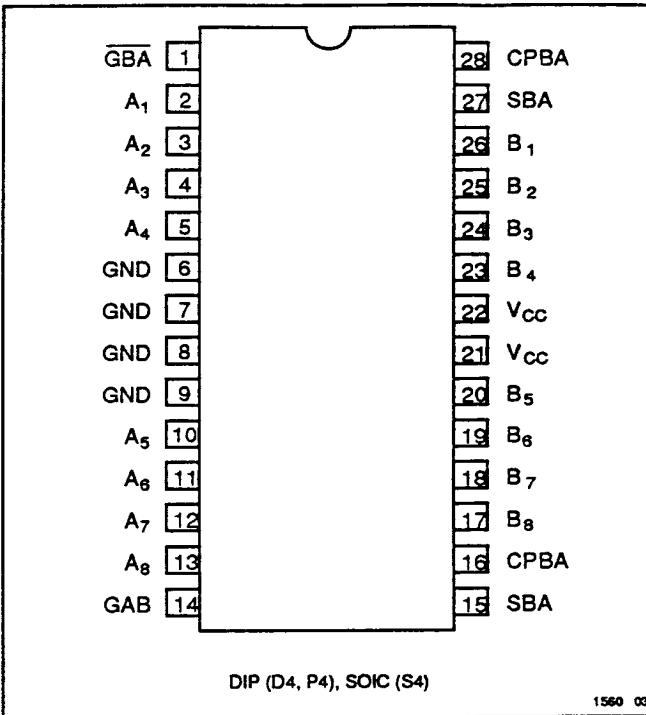
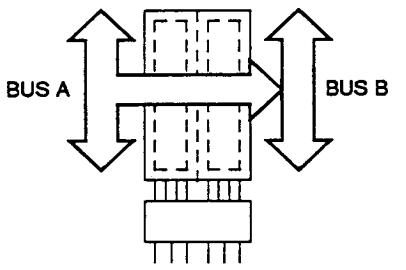
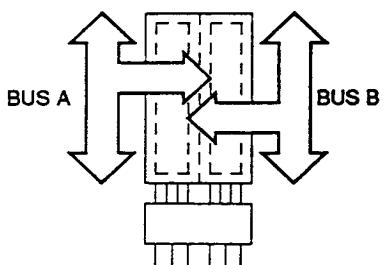
Means Quality, Service and Speed

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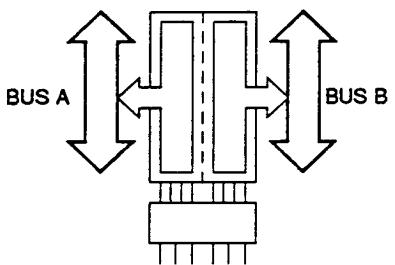
LOGIC SYMBOL**PIN DESCRIPTION**

Pin Names	Description
A ₁ –A ₈	Data Register A Inputs Data Register B Outputs
B ₁ –B ₈	Data Register B Inputs Data Register A Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
GAB, GBA	Output Enable Inputs

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LOGIC SYMBOLREAL-TIME TRANSFER
BUS B TO BUS AREAL-TIME TRANSFER
BUS A TO BUS B

GAB	$\overline{G\bar{B}A}$	CPAB	CPBA	SAB	SBA
X	H	\square	X	X	X
L	X	X	\square	X	X
L	H	\square	\square	X	X

STORAGE FROM
A AND/OR B

GAB	$\overline{G\bar{B}A}$	CPAB	CPBA	SAB	SBA
H	L	H or L	H or L	H	H

TRANSFER
STORED DATA
TO A AND/OR B

1560 04

FUNCTION TABLES

Inputs						Data I/O		Operation or Function	
GAB	GBA	CPAB	CPBA	SAB	SBA	A ₁ thru A ₈	B ₁ thru B ₈	'FCT651T	'FCT652T
L L	H H	H or L 	H or L 	X X	X X	Input	Input	Isolation Store A and B Data	Isolation Store A and B Data
X H	H H		H or L 	X X ²	X X	Input Input	Unspecified ¹ Output	Store A, Hold B Store A in both registers	Store A, Hold B Store A in both registers
L L	X L	H or L 		X X	X X ²	Unspecified ¹ Output	Input Input	Hold A, Store B Store B in both registers	Hold A, Store B Store B in both registers
L L	L L	X X	X H or L	X X	L H	Output	Input	Real-Time B Data to A Bus Stored B Data to A Bus	Real-Time B Data to A Bus Stored B Data to A Bus
H H	H H	X H or L	X X	L H	X X	Input	Output	Real-Time A Data to B Bus Stored A Data to B Bus	Real-Time A Data to B Bus Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus	Stored A Data to B Bus and Stored B Data to A Bus

Notes:

- The data output functions may be enabled or disabled by various signals at the GAB or GBA inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.
- Select control = L: clocks can occur simultaneously.
Select control = H: clocks must be staggered in order to load both registers.
H = HIGH, L = LOW, X = Don't Care, = LOW-to-HIGH Transition

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ABSOLUTE MAXIMUM RATINGS^{1,2}

Symbol	Parameter	Value	Unit
T _{STG}	Storage Temperature	-65 to +150	°C
T _A	Ambient Temperature Under Bias	-65 to +135	°C
V _{cc}	V _{cc} Potential to Ground	-0.5 to +5.0	V
I _{IN}	Input Current	-30 to +5.0	mA

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Notes:

1. Operation beyond the limits set forth in the above table may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range.

RECOMMENDED OPERATING CONDITIONS

Free Air Ambient Temperature	Min	Max
Military Commercial	-55°C 0°C	+125°C +70°C

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Symbol	Parameter	Value	Unit
I _{OUTPUT}	Current Applied to Output	120	mA
V _{IN}	Input Voltage	-0.5 to V _{cc} + 0.5	V
V _{OUT}	Voltage Applied to Output	-0.5 to V _{cc} + 0.5	V

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2. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V_{cc} or ground.

DC ELECTRICAL CHARACTERISTICS (Over recommended operating conditions)

Symbol	Parameter		Min	Typ ¹	Max	Units	V _{cc}	Conditions
V _{IH}	Input HIGH Voltage		2.0		V _{cc} + 0.5	V		
V _{IL}	Input LOW Voltage		-0.5		0.8	V		
V _H	Hysteresis			0.35		V		All inputs
V _{IK}	Input Clamp Diode Voltage			-0.7	-1.2	V	MIN	I _{IN} = -18mA
V _{OH}	Output HIGH Voltage	Military/Commercial (CMOS) Military (TTL) Commercial (TTL)	V _{cc} - 0.2 2.4 2.4	V _{cc}		V	MIN	I _{OH} = -300μA
V _{OL}	Output LOW Voltage	Military/Commercial (CMOS) Military (TTL) Commercial (TTL)		GND 0.3 0.3	0.2 0.55 0.55	V	MIN	I _{OL} = 300μA I _{OL} = 48mA I _{OL} = 64mA
I _H	Input HIGH Current (Except I/O Pins)				5	μA	MAX	V _{IN} = V _{cc}
I _L	Input LOW Current (Except I/O Pins)				-5	μA	MAX	V _{IN} = GND
I _H	Input HIGH Current (Except I/O Pins)				5	μA	MAX	V _{IN} = 2.7V
I _L	Input LOW Current (Except I/O Pins)				-5	μA	MAX	V _{IN} = 0.5V
I _H	Input HIGH Current (I/O Pins only)				15	μA	MAX	V _{IN} = V _{cc}
I _L	Input LOW Current (I/O Pins only)				-15	μA	MAX	V _{IN} = GND
I _H	Input HIGH Current (I/O Pins only)				15	μA	MAX	V _{IN} = 2.7V
I _L	Input LOW Current (I/O Pins only)				-15	μA	MAX	V _{IN} = 0.5V
I _{OS}	Output Short Circuit Current ²		-60	-120	-225	mA	MAX	V _{OUT} = 0.0V
C _{IN}	Input Capacitance ³			5	10	pF		All inputs
C _{VO}	I/O Capacitance ³			9	12	pF		All I/Os

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Notes:

1. Typical limits are at V_{cc} = 3.3V, T_A = +25°C ambient.
2. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect

operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

3. This parameter is guaranteed but not tested.

DC CHARACTERISTICS (Over recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Typ ¹	Max	Units	Conditions
I_{cc}	Quiescent Power Supply Current (CMOS inputs)	0.003	0.5	mA	$V_{cc} = \text{MAX}$, $f_1 = 0$, Outputs Open, $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
ΔI_{cc}	Quiescent Power Supply Current (TTL inputs)	0.5	2.0	mA	$V_{cc} = \text{MAX}$, $V_{in} = V_{cc} - 0.6V^2$, $f_1 = 0$, Outputs Open
I_{ccD}	Dynamic Power Supply Current ³	0.15	0.25	mA/MHz	$V_{cc} = \text{MAX}$, One Input Toggling, 50% Duty Cycle, Outputs Open GAB = GND, GBA = GND, SAB = CPAB = GND, SBA = V_{cc} , $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
I_c	Total Power Supply Current ⁵	1.7	4.0	mA	$V_{cc} = \text{MAX}$, $f_0 = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, One Bit Toggling at $f_1 = 5\text{MHz}$, GAB = GND, GBA = GND, SAB = CPAB = GND, SBA = V_{cc} , $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
		2.2	6.0	mA	$V_{cc} = \text{MAX}$, $f_0 = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, One Bit Toggling at $f_1 = 5\text{MHz}$, GAB = GND, GBA = GND, SAB = CPAB = GND, SBA = V_{cc} , $V_{in} = V_{cc} - 0.6V$ or $V_{in} = \text{GND}$
		7.0	12.8 ⁴	mA	$V_{cc} = \text{MAX}$, $f_0 = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at $f_1 = 2.5\text{MHz}$, GAB = GND, GBA = GND, SAB = CPAB = GND, SBA = V_{cc} , $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
		9.2	21.8 ⁴	mA	$V_{cc} = \text{MAX}$, $f_0 = 10\text{MHz}$, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at $f_1 = 2.5\text{MHz}$, GAB = GND, GBA = GND, SAB = CPAB = GND, SBA = V_{cc} , $V_{in} = V_{cc} - 0.6V$ or $V_{in} = \text{GND}$

Notes:

1. Typical values are at $V_{cc} = 3.3V$, $+25^\circ\text{C}$ ambient and maximum loading.
2. Per TTL driven input ($V_{in} = V_{cc} - 0.6V$); all other inputs at V_{cc} or GND.
3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
4. Values for these conditions are examples of the I_{cc} formula. These limits are guaranteed but not tested.
5. $I_c = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$
 $I_c = I_{cc} + \Delta I_{cc} \cdot D_H \cdot N_T + I_{ccD} (f_0/2 + f_1 N_1)$
 $I_c = \text{Quiescent Current with CMOS input levels}$

ΔI_{cc} = Power Supply Current for a TTL High Input ($V_{in} = V_{cc} - 0.6V$)

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{ccD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_0 = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_1 = Input Frequency

N_1 = Number of Inputs at f_1

All currents are in millamps and all frequencies are in megahertz.

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AC CHARACTERISTICS

Symbol	Parameter	'FCT3651C/3652C				'FCT3651D/3652D				Units	Fig. No.		
		MIL		COM'L		MIL		COM'L					
		Min. ¹	Max.										
t_{PLH} t_{PHL}	Propagation Delay Bus to Bus	1.5	6.0	1.5	5.4	1.5	5.4	1.5	4.6	ns	1, 3		
t_{PZH} t_{PZL}	Output Enable Time Enable to Bus and DIR to A or B	1.5	6.3	1.5	5.7	1.5	5.7	1.5	4.8	ns	1, 7, 8		
t_{PHZ} t_{PLZ}	Output Disable Time \bar{G} to Bus and DIR to Bus	1.5	7.0	1.5	6.2	1.5	6.2	1.5	5.3	ns	1, 7, 8		
t_{PLH} t_{PHL}	Propagation Delay Clock to Bus	1.5	8.9	1.5	7.8	1.5	7.8	1.5	6.6	ns	1, 5		
t_{PLH} t_{PHL}	Propagation Delay SBA or SAB to A or B	1.5	7.7	1.5	6.3	1.5	6.3	1.5	5.4	ns	1, 5		

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Note:

1. AC Characteristics guaranteed with $C_L = 50\text{pF}$ as shown in Figure 1.

AC OPERATING REQUIREMENTS

Symbol	Parameter	'FCT3651C/3652C				'FCT3651D/3652D				Units	Fig. No.		
		MIL		COM'L		MIL		COM'L					
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.				
$t_s(H)$ $t_s(L)$	Setup Time HIGH or LOW Bus to Clock	2.0	—	2.0	—	2.0	—	1.7	—	ns	4		
$t_h(H)$ $t_h(L)$	Hold Time HIGH or LOW Bus to Clock	1.5	—	1.5	—	1.5	—	1.3	—	ns	4		
$t_w(H)$ $t_w(L)$	Pulse Width, HIGH or LOW	5.0	—	5.0	—	5.0	—	3.4	—	ns	5		

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Notes:

1. Minimum limits are guaranteed but not tested on Propagation Delays.
2. With one data channel toggling, $t_w(L) = t_s(H) = 2.0\text{ns}$ and $t_s = t_h = 1.0\text{ns}$.

ORDERING INFORMATION

PxxFCT3 Temp. Class	xxxx Device type	xx Package	x Processing	Blank	Commercial
				M MB	Military MIL-STD-883, Class B
				P D SO	Plastic DIP CERDIP Small Outline IC
				651C 652C	Inverting Octal Transceiver/Register Non-inverting Octal Transceiver/Register
				651D 652D	Fast Inverting Octal Transceiver/Register Fast Non-inverting Octal Transceiver/Register
			74 54		Commercial Military

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